



# Chiral-Belle Compton eDet Work Update

# Chiral Belle SKB e- Polarization Upgrade Working Meeting December 2023

Michael Gericke

For the U. Manitoba Belle II / ChiralBelle Group

### With work mainly done by:

Nafis Niloy (U. Manitoba) Shefali Prabhakar (U. Manitoba) Laheji Mohammad (U. Manitoba) Kristofer Isaac (U. Manitoba) Omar Hassan (U. Manitoba)

# Some figures borrowed from:

Andre Schoening (U. Heidelberg) Heiko Augustin (U. Heidelberg) Alena Weber (KIT)

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## Outline

- Proposed eDet overview
- Formal overview of the HVMAPS operational principle
- Key HVMAPS performance parameters (present version of the chip)
- Detector development status (MOLLER/JLab Hall A) and adaptability for SKB
- Chip status (including possible upgrades)
- Open questions







- > Measure the number counts in each mode over equal time periods
- > For the experimental asymmetry from detector measurements:

$$A_{exp} = \frac{n^{+} - n^{-}}{n^{+} + n^{-}} = P_{\gamma} P_{e} A_{l}$$

- $\succ$   $P_{\gamma}$ : Photon polarization (from laser)
- $\succ$   $A_l$ : Theoretical Compton asymmetry (precisely known)
- $\succ$   $P_e$  : Electron (beam) polarization:







- Have to measure the polarization as a function of scattered photon and/or electron energy
- For the electrons energy is related to recoil momentum
- Measure scattered electron energy by deflection in magnetic field (beam line field ?)
  - Higher photon energy  $\rightarrow$  lower electron energy
  - Lower electron energy  $\rightarrow$  more bending away from primary beam
- Need to build a detector that can accurately measure electron deflection (distance away from primary beam at some specified distance)
- Either strip or pixel detector located close to the un-scattered (laser off) beam trajectory
- Multiple detectors along 25 m beamline stretch





- $\blacktriangleright$  eDet at z = 25 m produces very small spread in x/y over very few pixels
- > Would require an additional dispersive magnet with a fairly high field to improve this (probably not in the cards)



- > Maybe put small Be windows at selected locations with detectors at those locations
  - Pixel detectors not normally needed for this, but
  - Could have a couple of planes 🙀 at several locations to improve S/N and background rejection
  - Would require more simulations







- Have to use existing beam line dipoles to analyze the electron energy / hit rate correlation
- It would not be in a straight line-of-sight to Compton IP
- > Have to model transport or measure transverse polarization
- Possibly implement several small thin Beryllium windows in beampipe to allow electrons to exit primary beam vacuum at selected locations
- Position resolution of the eDet could be used to do tracking of the scattered beam electrons and reduce background and improve S/N
- Detectors could be located in air, right in front of the Be windows
- Current design for JLab Hall-A aims for 4 planes could have one of these at each location







# **Operational principle:**

- The final size of the individual chips is ~20 mm by 23 mm
- 64000 pixels per chip ( $80 \ \mu m \times 80 \ \mu m$ )
- Several of them are to be combined to form a plane of whatever size is needed









## Summary of HV-MAPS operation (with figures by Heiko Augustin, Alena Weber, and Andre' Schoening – U. Heidelberg)

- There are three distinct areas of the chip:
  - 1. The pixel area, in which each of the 64000 pixels include an amplifier and a line driver to connect the pixel to the periphery
  - 2. The mirror pixel area at the chip periphery, which includes two tunable ToT comparators
  - 3. Three state machines at the chip periphery and a mux for data transfer







- Signal digitization and time stamp generation:
  - 1. Each pixel drives the amplified hit signal to a dedicated readout buffer at the chip periphery
  - 2. The two comparators for each pixel are part of the readout buffer circuitry
  - 3. The readout buffer generates two timestamps. The first one sets the hit latch. The second one establishes the ToT proportional to the collected charge and reduces time-walk effects.
  - 4. The buffer stores an 8b pixel row address and the two timestamps (TS1 = 11b and TS2 = 5b)



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- Chip event readout organization:
  - 1. The chip is readout in column-drain and row readout sequence. There are 250 rows and 256 columns
  - 2. Pixels buffers with hits are transferred to an EoC (End of Column) cell, selected by a priority logic.
  - 3. If a pixel buffer hit state is transferred to the corresponding EoC, the buffer is cleared and the pixel is sensitive to new hits again.
  - 4. The EOC contains an 8b column address and collects the full 32b hit information
  - 5. The priority chain within a column is based on pixel position and hit time
  - 6. The state machine generates signals to transfer the pixel hit information to the EoC and transfer the 32 bit EoC data to the serializer
  - 7. The 32b data words are byte serialized and 8b/10b encoded











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**Event Sequence:** 

Signal







- **Event Sequence:**
- Signal
- Amplification







- Signal
- Amplification
- Transmission to periphery







- Signal
- Amplification
- Transmission to periphery
- Storage in the buffer (pixel cleared for next event)







- Signal
- Amplification
- Transmission to periphery
- Storage in the buffer (pixel cleared for next event)
- Digitization of the hit







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- Signal
- Amplification
- Transmission to periphery
- Storage in the buffer (pixel cleared for next event)
- Digitization of the hit
- Scalar generated from clk







- Signal
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- Transmission to periphery
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- Scalar generated from clk
- Timestamp generation







- Signal
- Amplification
- Transmission to periphery
- Storage in the buffer (pixel cleared for next event)
- Digitization of the hit
- Scalar generated from clk
- Timestamp generation
- Hit/pixel address and timestamp sent to serializer







**Event Sequence:** 

- Signal
- Amplification
- Transmission to periphery
- Storage in the buffer (pixel cleared for next event)
- Digitization of the hit
- Scalar generated from clk
- Timestamp generation
- Hit/pixel address and timestamp sent to serializer
- Data sent to readout board

Maximum readout rate is 33 MHz per link with a maximum of 3 links per chip.







Minor modifications to final chip:

- Match the on-chip clk to the CERN readout chip frequency
- A simple AND with a GATE link before each pixel buffer to turn on/off the readout – timed to choice to reduce pixel occupancy

These changes are relatively simple and underway.

Need to resubmit for one more engineering run

Then go to chip production – hopefully at the end of the year





# **Readout Setup**

We need to design and prototype a readout board that incorporates 4 IpGBT chips and 1 VTRx+, plus bias and LV power supply distribution.

**Starting point:** The bord schematics/design is available to us from CERN.

We can remove quite a few of the test/diagnostic components and want to make the board smaller for the ring 5 detectors, while incorporating 4 IpGBTs rather than 1.

Development is ongoing:

We have access to an engineer at Carleton Univ. through the Canadian SAP Major Resources Support network

To be mostly completed by end of June







# **Readout Setup:**

- We want 3 IpGBTs in slave mode and 1 IpGBT as master
- Slow-Control the lpGBTs via the of the down/uplink data stream from the back-end FPGA. This field allows to read and write the internal registers if the chip operates as a Transceiver (master).
- The VTRX+ has 4 uplinks (10.24 Gb/s) and one downlink (2.56 Gb/s) so we can read out
- Need to determine if we need the FEASTMP DC/DC converters or can run via remote power control
- We can use the Samtec <u>ASP-134486-01</u> FMC connector (female)
- Maximum board width 100 mm
- Maximum board length 200 mm
- Mounting holes can be relocated within the lower 50 mm of the board.
- Maximum hit readout rate per chip presently at ~90 Mhits / per second



Present design for the readout boar the layout stage.





# Back-end DAQ:

- Need an array of commercial FPGA boards like the Xilinx kcu105
- Or something like the Arista 48/96 LS fiber switch



#### From VTRX+ CERN Manual

#### Hardware

Description		Price	Qty	Ext. Price
DCS-7130-48LS-F	Arista 7130 Series 48L with UltraScale VU7P-2 FPGA, front-to-rear air, 2xAC v2	\$31,027.07	1	\$31,027.07
SVC-7130-48LS- 1M-NB	1-Month A-Care Software & NBD Hardware Replacement/Same Day Ship for 7130-48LS	\$294.55	60	\$17,673.00
DCS-7130-96LS-F	Arista 7130 Series 96L with UltraScale VU7P-2 FPGA, front-to-rear air, 2xAC v2	\$51,041.78	1	\$51,041.78
SVC-7130-96LS- 1M-NB	1-Month A-Care Software & NBD Hardware Replacement/Same Day Ship for 7130-96LS	\$483.06	60	\$28,983.60
SFP-10G-SR-P	Arista 10GBASE-SR SFP+ (Short Reach)	\$74.80	48	\$3,590.40
TARIFF FEE	Logistics Fee	\$8,258.66	1	\$8,258.66
FREIGHT.	Shipping & Handling	\$150.00	1	\$150.00
Subtotal:				

Quote Summary	Amount
Hardware	\$140,724.51
Subtotal:	\$140,724.51
Estimated GST:	\$7,036.22
Estimated PST:	\$9,850.71
Total:	\$157,611.44



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### Main detector low voltage cables and power supplies

## 2. HVMAPS

- 84 modules with 28 chips per module. Need three different LV connections for each module (2*V*, 1.2*V*, 2.5*V*) and one "HV" connection (≲ 100 *V*) for bias
- LV powers the chip itself and the readout electronics

### Per Module:

- Chip supply voltage:  $V_{chip} = 2V @ 0.5A \times 28$  (parallel)
- Readout IpGBT:  $V_{lpBGT} = 1.2V @ 0.27A \times 4$
- Readout VTRX+:  $V_{VTRX} = 1.2V @ 0.045A + 2.5V @ 0.080A$
- Bias:  $V_{bias} = 100V @ 0.02A$
- Largest power:  $P_{chips} \simeq 34 W$  (includes ~20% safety factor)
- Total power:  $P_{tot} \simeq 38 W$  (includes ~20% safety factor)

### Cables:

- Voltage drops:
  - Flexprint to R5 readout:  $\Delta V \sim 0.15 V @ 3.5 A$ ٠ R5 readout to segment patch panel:  $\Delta V \sim 0.16V$  @ 3.5 A AWG 18 (VDD + GND = 24 cables/segment) ٠  $\Delta V \sim 0.56V$  @ 1.75 A AWG 15 (Split VDD and GND into two AWG 15 = 48 cables) Segment patch panel to GEM hut: ٠ GEM hut floor to PS unit:  $\Delta V \sim 0.12V @ ? A$ AWG ? (Depends on PS unit we choose) ٠ Total:  $\Delta V \leq 1V$ (Depending on PS unit we chose) ٠





# Main detector low voltage cables and power supplies

2. HVMAPS

### **PSU Series**

• Single channel high current

SPECIFICATIONS	
MODEL	PSU 6-200
OUTPUT RATINGS	
Rated Output Voltage (*1) Rated Output Current (*2) Rated Output Power	6V 200A 1200W
RIPPLE AND NOISE(*5)	120011
CVp-p( 10 ~ 20MHz) p-p (*6) CVrms(5Hz ~ 1MHz) r.m.s. (*7) CCrms(5Hz ~ 1MHz) r.m.s.(*12)	60mV 8mV 400mA
LOAD REGULATION	
Voltage(*4) Current(*11)	2.6mV 45mA
LINE REGULATION	
Voltage(*3) Current(*3)	2.6mV 22mA







- Compton e-Detector design for in-vacuum operation:
  - 4 pixel detector planes
  - HVMAP pixel detectors
  - 3  $2 \times 2 \ cm^2$  chips per plane (TBD based on profile)
  - $80 \times 80 \ \mu m$  pixels
  - Original chip design based on ATLASPix & MuPix (designed at KIT, Heidelberg, Mainz)
  - Specific modifications for probably required for ChiralBelle (faster chip/readout)

Mounting and cooling structure design: Nafis Niloy and Kristofer Isaac



New HVMAPS detector planes





- Compton e-Detector design for in-vacuum operation :
  - Each detector plane consists of 3 HVMAPS wire-bonded to a metal-core PCB
  - Two planes will be attached to one cooling block, interfaced together using thermal pads
  - Cooling block will be a single piece of machined copper (different color used in figure for ease of visibility)







Compton e-Detector design for in-vacuum operation :

PCB and readout design: Jie Pan

- HVMAPS will be glued and wire-bonded to a PCB
- Metal-core PCB will help conduct heat produced by the HVMAPS away for dissipation
- Using thermal pads to improve thermal conduction between metalcore PCB and HVMAPS









- Compton e-Detector design for in-vacuum operation :
  - A prototype of the Compton heat exchanger was designed and machined out of copper
  - Rather than manufacturing the custom copper feedthrough cylinder planned for the final design, the prototype model utilizes separate chilled water lines fitted to the heat exchanger with compression fittings to reduce prototype costs and leverage existing vacuum infrastructure
  - Next steps for prototype:
    - Pre-test seal of prototype heat exchanger using pneumatic pressure-differential test
    - Fully assemble Compton prototype heat exchanger, including chilled water lines
    - Assemble Compton test planes onto heat blocks



Fig. Prototype heat blocks

Fig. Prototype heat exchanger, featuring double o-ring grooves and turbulence-generator tab



Fig. Rough layout of heat exchanger prototype, including chilled water feed-through flange

Savino Longo, Compton HVMAPS update, Belle II Collaboration

Meeting





> Cooling studies:



Temperature distribution of overall assembly

## Thermal simulations and measurement setup: Shefali Prabhakar



Temperature variation of coolant inside the heat exchanger

Savino Longo, Compton HVMAPS update, Belle II Collaboration



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2023-12-12



# Recent work updates and status:

The aim of this setup is to test cooling capabilities in vacuum

Goal is to verify modeled cooling performance with measured

Thermal simulations of the same model as shown below.

Cooling studies:

### Thermal simulations and measurement setup: Shefali Prabhakar

Fig.b

Currently using dummy (heater) chips

temperature gradients at various positions





A.) Combination of resistors as a heating element.



B.) Nichrome wire as a heating element





> Cooling studies:



- Both cooling blocks will be attached to either side of the copper heat exchanger using 5 fasteners (red arrows)
- Applies a clamping pressure of 4000 psi between mating heat-exchanger components
- Maximizes conduction between components
- Heat exchanger will be machined out of a single block of copper
- Distance between two adjacent HVMAPS planes is 12.6 mm





Cooling studies:



- Shaft holding the assembly in ٠ beam line will be attached to a linear translation stage to move detector planes up and down
- Translation stage attached via a ٠ feed-through
- Shaft will be a copper rod with ٠ coolant channels bored along its length
- Will be using LCW (Low • Conductive Water) as coolant
- Pocket is designed to make the ٠ flow of coolant turbulent, thereby increasing heat transfer to coolant
- Shaft and heat exchanger will be ٠ brazed to prevent possible leaks





# **Chip Development Status:**

- > The most recent version of the chip as described in this document was produced by TSI
- TSI was taken over by Bosch in September and the foundry will be shut down at the end of 2023 no further production of these types of chips will take place through TSI/Bosch after that we have enough to build the Hall A Compton detectors but not for any future development
- There is presently a community wide search for alternatives
- > We have identified AMS as a suitable alternative with some design changes
  - Intermediate design changes in the short run to be submitted for an engineering run in April, with evaluation in the Summer months
  - Possible production run in the Fall
  - Additional design changes and engineering runs possible in 2025 ...
    - For Chiral Belle: Making the chip faster (?)
    - Higher resolution (?)
    - ...





# **Questions / unresolved issues:**

- Are these detectors suitable ?
  - Too slow, resolution too low, ...
- Establish detector position
- How many positions/detectors
- > Continue simulations (money available through the NSERC operating grant Wouter will look for student for next year )
- > DAQ and system interface and requirements
- Floor plans / where can we put how much stuff





Backups





# **Readout Setup:**

## **Chip-to-flexprint connections:**

- Single LVDS pair readout per chip at ~180 Mbps
- 7 chips ~ 1.28 Gbps
- 14 lines per chip through flexprint and ribbon
- Clk\_P/N from lpGBT
- S\_In\_P/N chip addressing through IpGBT slow control
- SYNC\_RES\_P/N chip gating (or similar) also through IpGBT
- Rest of the lines are voltage distribution

VDD -	VDD				MRY
CLK N -	CLK_N			1	CLK N
	CLK_P			2	CLK P
	SINN			3	
S_IN_N -	S_IN_P			4	S_IN_N S_IN_P
0					
DATA_A_P -	DATA_A_P			5	DATA_A_P
DATA_A_N -	DATA_A_N			6	DATA_A_N
DATA_B_P	DATA B P			7	DATA_B_P
DATA_B_N	DATA_B_N			8	DATA_B_N
DATA_C_P -	DATA_C_P		_	9	DATA_C_P
DATA_C_N -	DATA_C_N			10	DATA_C_N
Reset/gate				12	SYNC_RES_P
				13	SYNC_RES_N
				14	
				15	V OUT DL
		•		16	VDDD_L1
		•		17	VDDD_L2
			•	18	V_IN_AL
			•	19	SHUNT_AL
			1	20	V_OUT_AL
		t		22	VDDA_L1
				23	V OUT SL
				24	VSSA L
				25	GNDD_1
			•	26	GNDA_1
TEMPERATURE -				21	TEMPERATURE
A_0 -	A 1			X	
A_1 -	A_2			Č	
A_2 -	A_3			$\sim$	
CON_RESISTOR	CON RESISTOR			$-\hat{\mathbf{x}}$	
	VDD SENSE			33	
GND SENSE	GND_SENSE			34	V_HIGH
OND_OENOL				35	USE SPI
		•		36	ENABLE_SC
				37	DOWED ON DEALT
				38	POWER_ON_RESET
				39	V IN DR
				40	SHUNT_DR
			•	41	V_OUT_DR
		+		42	VDDD_R1
		†		43	VDDD_R2
			1	45	V_IN_AR
				46	V OUT AR
		•		47	VDDA_R1
		•		48	VDDA_R2
		[		49	V_OUT_SR
		L		51	VSSA_R
			1	52	GNDD_2
			1		GNDA_2
		•		53	VDDD_R3
			•	54	GNDD_3
		L		55	VDDA_R3
			•	30	GNDA_3
HV -	HV			57	SUBSTRATE
· · · · · · · · · · · · · · · · · · ·	010				



- Chip connections:
  - 1. There will be 4 differential outputs (8 lines) per chip that are connected to the lpGBT:
    - 1. Clock (Clk\_n/p)
    - 2. Data-out (DOut\_n/p)
    - 3. Gate\_n/p
    - 4. Addressing (Sin\_n/p)
  - 2. There could be one more digital temperature signal from each chip to the lpGBT input (TBD)
  - 3. All signals except the temperature diode are LVDS
  - 4. Target TX speed is 1.28 Gbps (~180 Mbps per chip to lpGBT)
  - 5. Target RX speed is 80 Mbps (from lpGBT to chip)



# VLDB:

- Item 1: Core parts needed 4 lpGBT, 1 VTRX+
- Item 2: FEASTMP may not be needed. Use remote power from PS unit (see slide 6) need to implement a sense wire maybe can use them though
- Item 3: Not needed mode selection should take place via the downlink interface
- Item 4: Needs to be re-designed to supply power to the IpGBTs , the VTRX+, and to the HCMAPS chips
- Item 5: Not needed startup configuration and operation mode need to be "hard wired" by pulling control pins high/low with resistors
- Item 6: Not needed
- Item 7: Not needed reference clock should come through downlink, but the lower two connectors could be kept for benchtop testing/prototyping
- Item 8: Could be kept for prototype testing
- Item 9: Not needed but might be useful for testing





# **VTRX+ Info:**

- Fiber optic transceiver ٠
- 4 upstream channels (sum = 10.24 Gb/s) ٠
- 1 downstream channel (2.56 Gb/s) ٠
- 20 cm pigtail with female MT terminator ٠
- Needs to have MT-MPO (male) adapter or other to connect to ٠ standard fiber





Up to 4Tx plus 1Rx

on-board 12Tx, 12Rx module







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